IN THE CLAIMS

- 1 (Currently Amended). A method comprising:

 exposing a contact plug fill to an etching solution; and

 exposing the surface of said contact plug fill to an electrical charge using voltage

 contrast-based defect inspection. determining if the region under the contact plug fill is etched

 away.
- 2 (Original). The method of claim 1 including exposing the contact plug fill to a basic solution.
- 3 (Original). The method of claim 1 including exposing the contact plug fill to a solution that preferably etches along the <111> crystallographic orientation
- 4 (Original). The method of claim 1 including using an etching solution that etches a characteristic etch pattern under the contact plug fill if the contact plug fill is defective.

Claims 5-7 (Canceled).

8 (Currently Amended). The method of claim 1 5 including determining which contact plug fill dissipates surface charge and which contact plug fill does not dissipate surface charge.

9 (Original). A method comprising:

forming a conductive material in an aperture in a dielectric layer; and applying an etching solution to said conductive material to determine whether the conductive material is defective.

10 (Original). The method of claim 9 including exposing a contact plug fill to an etching solution.

- 11 (Original). The method of claim 9 including applying an etching solution which characteristically etches underneath the conductive material if the conductive material is defective.
- 12 (Original). The method of claim 9 including applying a basic solution to said conductive material.
- 13 (Original). The method of claim 9 wherein applying an etching solution includes exposing the conductive material to a solution that preferentially etches along the <111> crystallographic direction.
- 14 (Original). The method of claim 12 including applying an etching solution that etches a V-shaped trench under a defective conductive material.
- 15 (Original). The method of claim 9 including exposing the surface of said conductive material to an electric charge.
- 16 (Original). The method of claim 15 including using voltage contrast-based defect inspection.
- 17 (Original). The method of claim 9 including applying a contact to said conductive material.
- 18 (Original). The method of claim 17 including using electrical testing to determine if said conductive material is defective.
- 19 (Original). The method of claim 15 including using a secondary electron image to determine if said conductive material is defective.

20 (Currently Amended). A method comprising:

forming a contact plug fill in a dielectric layer;

applying a basic solution to said contact plug fill to etch a V-shaped trench under a defective fill; and

determining whether the region underneath the contact plug fill is etched by said basic solution.

- 21 (Original). The method of claim 20 including applying a basic solution which characteristically etches underneath the contact plug fill if the fill is defective.
- 22 (Original). The method of claim 20 wherein applying a basic solution includes exposing the contact plug fill to a solution that preferentially etches along the <111> crystallographic direction.

Claim 23 (Canceled).

- 24 (Original). The method of claim 20 including exposing the contact plug fill to an electric charge.
- 25 (Original). The method of claim 24 including using voltage contrast-based defect inspection.
- 26 (Original). The method of claim 20 including applying a contact to said contact plug fill.
- 27 (Original). The method of claim 21 including using electrical testing to determine if said fill is defective.
- 28 (Original). The method of claim 24 including using a secondary electron image to determine if said fill is defective.